



MOS FIELD EFFECT TRANSISTOR 2SK3386

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3386 is N-Channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Low On-state Resistance
- ★ $R_{DS(on)1} = 21 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, I_D = 17 \text{ A})$
- $R_{DS(on)2} = 36 \text{ m}\Omega \text{ MAX.} (V_{GS} = 4.0 \text{ V}, \text{ ID} = 17 \text{ A})$
 - Low C_{iss} : $C_{iss} = 2100 \text{ pF TYP}$.
 - Built-in Gate Protection Diode
 - TO-251/TO-252 package

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

	Drain to Source Voltage	VDSS	60	V
	Gate to Source Voltage	Vgss	±20	V
	Drain Current (DC)	D(DC)	±34	А
\star	Drain Current (Pulse) Note1	D(pulse)	±120	А
*	Total Power Dissipation (Tc = 25°C)	Рт	40	W
	Total Power Dissipation (TA = 25°C)	Рт	1.0	W
	Channel Temperature	Tch	150	°C
	Storage Temperature	Tstg	–55 to +150	°C
\star	Single Avalanche Current Note2	las	28	А
\star	Single Avalanche Energy ^{Note2}	Eas	78	mJ

ORDERING INFORMATION

PART NUMBER	PACKAGE	
2SK3386	TO-251	
2SK3386-Z	TO-252	



(TO-251)

(TO-252)



Notes 1. PW \leq 10 μ s, Duty cycle \leq 1 %

2. Starting T_{ch} = 25 °C, R_G = 25 Ω , V_{GS} = 20 V \rightarrow 0 V

THERMAL RESISTANCE

*	Channel to Case	Rth(ch-C)	3.13	°C/W
	Channel to Ambient	Rth(ch-A)	125	°C/W

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90 %

90 %

tſ

toff

10 %

VGS(on)

lо

td(off)

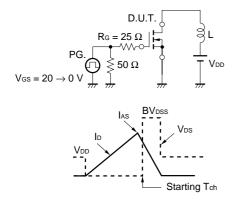
★ ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

NEC

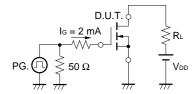
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 17 A		17	21	mΩ
	RDS(on)2	Vgs = 4.0 V, Id = 17 A		25	36	mΩ
Gate to Source Cut-off Voltage	V _{GS(off)}	$V_{DS} = 10 V, I_{D} = 1 mA$	1.5	2.0	2.5	V
Forward Transfer Admittance	y _{fs}	Vds = 10 V, Id = 17 A	10	19		S
Drain Leakage Current	Ibss	Vds = 60 V, Vgs = 0 V			10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μA
Input Capacitance	Ciss	V _{DS} = 10 V		2100		pF
Output Capacitance	Coss	Vgs = 0 V		340		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		170		pF
Turn-on Delay Time	t d(on)	ID = 17 A		32		ns
Rise Time	tr	$V_{GS(on)} = 10 V$		310		ns
Turn-off Delay Time	td(off)	Vdd = 30 V		98		ns
Fall Time	tr	Rg = 10 Ω		100		ns
Total Gate Charge	Q _G	ID = 34 A		39		nC
Gate to Source Charge	Q _{GS}	Vdd = 48 V		7.0		nC
Gate to Drain Charge	Qgd	VGS(on) = 10 V		12		nC
Body Diode Forward Voltage	VF(S-D)	IF = 34 A, VGS = 0 V		0.87		V
Reverse Recovery Time	trr	IF = 34 A, VGS = 0 V		46		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		84		nC

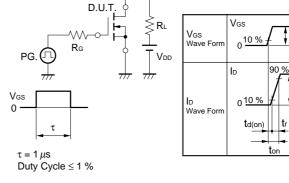
TEST CIRCUIT 1 AVALANCHE CAPABILITY

TEST CIRCUIT 2 SWITCHING TIME



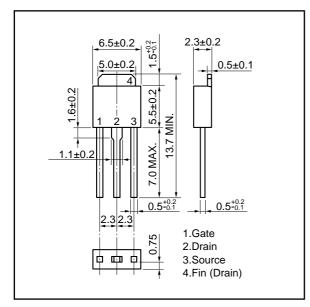
TEST CIRCUIT 3 GATE CHARGE



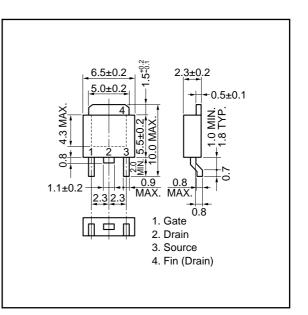


PACKAGE DRAWINGS (Unit : mm)

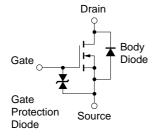
1) TO-251 (MP-3)



2) TO-252 (MP-3Z)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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